

Dual/Quad, Low Power CMOS Operational Amplifiers

The ICL761X/762X/764X series is a family of monolithic CMOS operational amplifiers. These devices provide the designer with high performance operation at low supply voltages and selectable quiescent currents. They are an ideal design tool when ultra low input current and low power dissipation are desired.

The basic amplifier will operate at supply voltages ranging from $\pm 1V$ to $\pm 8V$, and may be operated from a single Lithium cell. The output swing ranges to within a few millivolts of the supply voltages.

The quiescent supply current of these amplifiers is set to 3 different ranges at the factory. Both amps of the dual ICL7621 are set to an I_Q of $100\mu A$, while each amplifier of the quad ICL7641 and ICL7642 are set to an I_Q of $1mA$ and $10\mu A$ respectively. This results in power consumption as low as $20\mu W$ per amplifier.

Of particular significance is the extremely low ($1pA$) input current, input noise current of $0.01pA/\sqrt{Hz}$, and $10^{12}\Omega$ input impedance. These features optimize performance in very high source impedance applications.

The inputs are internally protected. Outputs are fully protected against short circuits to ground or to either supply.

AC performance is excellent, with a slew rate of $1.6V/\mu s$, and unity gain bandwidth of $1MHz$ at $I_Q = 1mA$.

Because of the low power dissipation, junction temperature rise and drift are quite low. Applications utilizing these features may include stable instruments, extended life designs, or high density packages.

Ordering Information

PART NUMBER	TEMP. RANGE (°C)	PACKAGE	PKG. NO.
ICL7621ACPA	0 to 70	8 Ld PDIP - A Grade - $I_Q = 100\mu A$	E8.3
ICL7621BCPA	0 to 70	8 Ld PDIP - B Grade - $I_Q = 100\mu A$	E8.3
ICL7621DCPA	0 to 70	8 Ld PDIP - D Grade - $I_Q = 100\mu A$	E8.3
ICL7621AMTV	-55 to 125	8 Pin Metal Can - A Grade - $I_Q = 100\mu A$	T8.C
ICL7621DCBA	0 to 70	8 Ld SOIC - D Grade - $I_Q = 100\mu A$	M8.15
ICL7621DCBA-T	0 to 70	8 Ld SOIC - D Grade - Tape and Reel - $I_Q = 100\mu A$	M8.15
ICL7641ECPD	0 to 70	14 Ld PDIP - E Grade - $I_Q = 1mA$	E14.3
ICL7642ECPD	0 to 70	14 Ld PDIP - E Grade - $I_Q = 10\mu A$	E14.3

Features

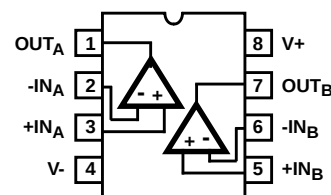
- Wide Operating Voltage Range $\pm 1V$ to $\pm 8V$
- High Input Impedance $10^{12}\Omega$
- Input Current Lower Than BIFETs $1pA$ (Typ)
- Output Voltage Swing $V+$ and $V-$
- Available as Duals and Quads (Refer to ICL7611 for Singles)
- Low Power Replacement for Many Standard Op Amps

Applications

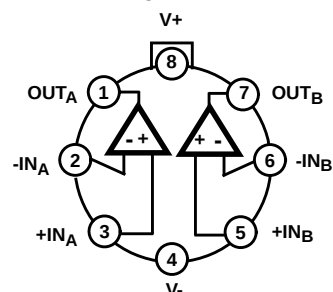
- Portable Instruments
- Telephone Headsets
- Hearing Aid/Microphone Amplifiers
- Meter Amplifiers
- Medical Instruments
- High Impedance Buffers

Pinouts

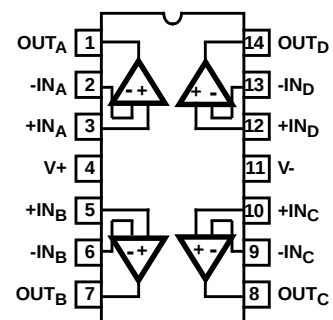
ICL7621 (PDIP, SOIC)
TOP VIEW



ICL7621 (METAL CAN)
TOP VIEW



ICL7641 (PDIP), ICL7642 (PDIP)
TOP VIEW



Absolute Maximum Ratings

Supply Voltage V+ to V-18V
 Input Voltage V- -0.3 to V+ +0.3V
 Differential Input Voltage (Note 1) [(V+ +0.3) - (V- -0.3)]V
 Duration of Output Short Circuit (Note 2)..... Unlimited

Operating Conditions

Temperature Range
 ICL76XXM -55°C to 125°C
 ICL76XXC 0°C to 70°C

Thermal Information

Thermal Resistance (Typical, Note 3) θ_{JA} (°C/W) θ_{JC} (°C/W)
 SOIC Package 160 N/A
 Metal Can Package 160 75
 8 Lead PDIP Package 120 N/A
 14 Lead PDIP Package 80 N/A
 Maximum Junction Temperature (Hermetic Packages).....175°C
 Maximum Junction Temperature (Plastic Package)150°C
 Maximum Storage Temperature Range..... -65°C to 150°C
 Maximum Lead Temperature (Soldering 10s) 300°C
 (SOIC - Lead Tips Only)

CAUTION: Stresses above those listed in "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress only rating and operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied.

NOTES:

1. Long term offset voltage stability will be degraded if large input differential voltages are applied for long periods of time.
2. The outputs may be shorted to ground or to either supply, for $V_{SUPPLY} \leq 10V$. Care must be taken to insure that the dissipation rating is not exceeded.
3. θ_{JA} is measured with the component mounted on an evaluation PC board in free air.

Electrical Specifications $V_{SUPPLY} = \pm 5V$, Unless Otherwise Specified

PARAMETER	SYMBOL	TEST CONDITIONS	TEMP. (°C)	ICL7621A			ICL7621B			ICL7621D			UNITS
				MIN	TYP	MAX	MIN	TYP	MAX	MIN	TYP	MAX	
Input Offset Voltage	V_{OS}	$R_S \leq 100k\Omega$	25	-	-	2	-	-	5	-	-	15	mV
			Full	-	-	3	-	-	7	-	-	20	mV
Temperature Coefficient of V_{OS}	$\Delta V_{OS}/\Delta T$	$R_S \leq 100k\Omega$	-	-	10	-	-	15	-	-	25	-	$\mu V/^\circ C$
Input Offset Current	I_{OS}		25	-	0.5	30	-	0.5	30	-	0.5	30	pA
			0 to 70	-	-	300	-	-	300	-	-	300	pA
			-55 to 125	-	-	800	-	-	800	-	-	800	pA
Input Bias Current	I_{BIAS}		25	-	1.0	50	-	1.0	50	-	1.0	50	pA
			0 to 70	-	-	400	-	-	400	-	-	400	pA
			-55 to 125	-	-	4000	-	-	4000	-	-	4000	pA
Common Mode Voltage Range	V_{CMR}	$I_Q = 100\mu A$	25	± 4.2	-	-	± 4.2	-	-	± 4.2	-	-	V
Output Voltage Swing	V_{OUT}	$I_Q = 100\mu A$, $R_L = 100k\Omega$	25	± 4.9	-	-	± 4.9	-	-	± 4.9	-	-	V
			0 to 70	± 4.8	-	-	± 4.8	-	-	± 4.8	-	-	V
			-55 to 125	± 4.5	-	-	± 4.5	-	-	± 4.5	-	-	V
Large Signal Voltage Gain	A_{VOL}	$V_O = \pm 4.0V$, $R_L = 100k\Omega$, $I_Q = 100\mu A$	25	86	102	-	80	102	-	80	102	-	dB
			0 to 70	80	-	-	75	-	-	75	-	-	dB
			-55 to 125	74	-	-	68	-	-	68	-	-	dB
Unity Gain Bandwidth	GBW	$I_Q = 100\mu A$	25	-	0.48	-	-	0.48	-	-	0.48	-	MHz
Input Resistance	R_{IN}		25	-	10^{12}	-	-	10^{12}	-	-	10^{12}	-	Ω
Common Mode Rejection Ratio	CMRR	$R_S \leq 100k\Omega$, $I_Q = 100\mu A$	25	76	91	-	70	91	-	70	91	-	dB
Power Supply Rejection Ratio ($V_{SUPPLY} = \pm 8V$ to $\pm 2V$)	PSRR	$R_S \leq 100k\Omega$, $I_Q = 100\mu A$	25	80	86	-	80	86	-	80	86	-	dB
Input Referred Noise Voltage	e_N	$R_S = 100\Omega$, $f = 1kHz$	25	-	100	-	-	100	-	-	100	-	$nV/\sqrt{Hz}$
Input Referred Noise Current	i_N	$R_S = 100\Omega$, $f = 1kHz$	25	-	0.01	-	-	0.01	-	-	0.01	-	$pA/\sqrt{Hz}$
Supply Current (Per Amplifier)	I_{SUPPLY}	No Signal, No Load, $I_Q = 100\mu A$	25	-	0.1	0.25	-	0.1	0.25	-	0.1	0.25	mA

ICL7621, ICL7641, ICL7642

Electrical Specifications

V_{SUPPLY} = ±5V, Unless Otherwise Specified (Continued)

PARAMETER	SYMBOL	TEST CONDITIONS	TEMP. (°C)	ICL7621A			ICL7621B			ICL7621D			UNITS
				MIN	TYP	MAX	MIN	TYP	MAX	MIN	TYP	MAX	
Channel Separation	V _{O1} /V _{O2}	A _V = 100	25	-	120	-	-	120	-	-	120	-	dB
Slew Rate	SR	A _V = 1, C _L = 100pF, V _{IN} = 8V _{P-P} , I _Q = 100μA, R _L = 100kΩ	25	-	0.16	-	-	0.16	-	-	0.16	-	V/μs
Rise Time	t _R	V _{IN} = 50mV, C _L = 100pF, I _Q = 100μA, R _L = 100kΩ	25	-	2	-	-	2	-	-	2	-	μs
Overshoot Factor	OS	V _{IN} = 50mV, C _L = 100pF, I _Q = 100μA, R _L = 100kΩ	25	-	10	-	-	10	-	-	10	-	%

Electrical Specifications

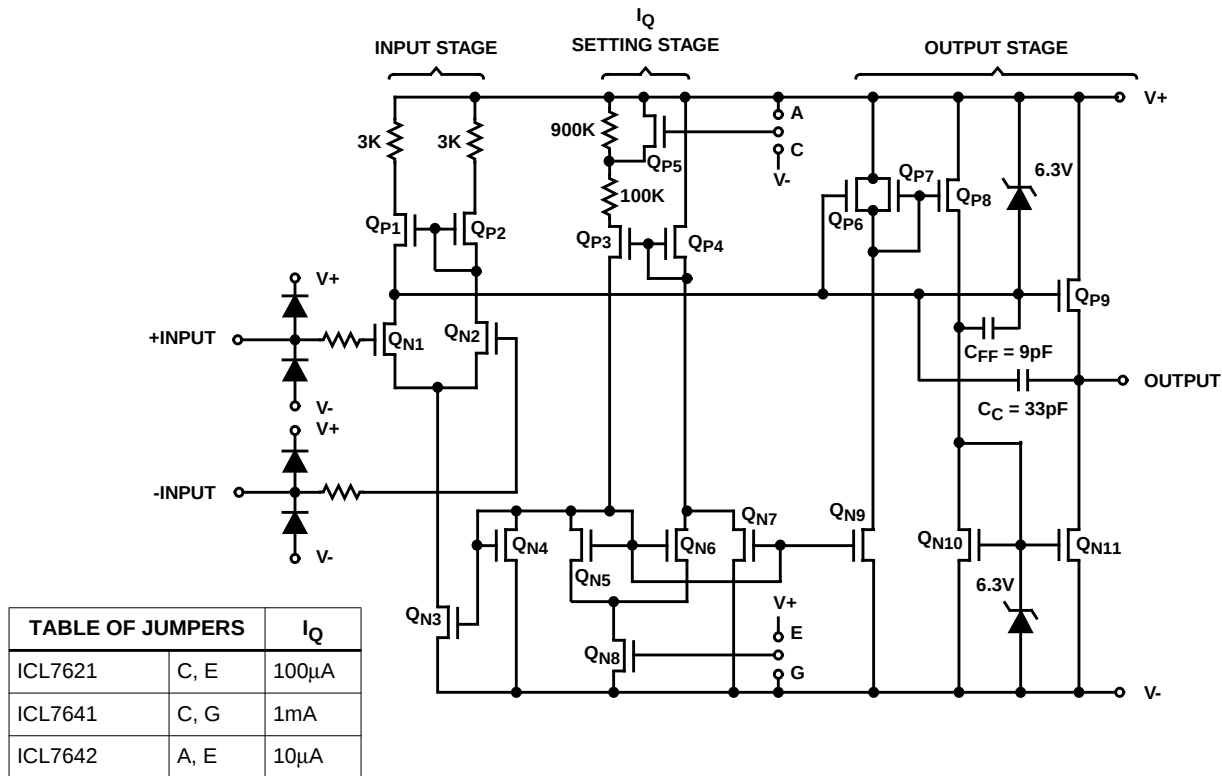
V_{SUPPLY} = ±5V, Unless Otherwise Specified

PARAMETER	SYMBOL	TEST CONDITIONS	TEMP. (°C)	ICL7641E, ICL7642E			UNITS
				MIN	TYP	MAX	
Input Offset Voltage	V _{OS}	R _S ≤ 100kΩ	25	-	-	20	mV
			Full	-	-	25	mV
Temperature Coefficient of V _{OS}	ΔV _{OS} /ΔT	R _S ≤ 100kΩ	-	-	30	-	μV/°C
Input Offset Current	I _{OS}		25	-	0.5	30	pA
			0 to 70	-	-	300	pA
			-55 to 125	-	-	800	pA
Input Bias Current	I _{BIAS}		25	-	1.0	50	pA
			0 to 70	-	-	500	pA
			-55 to 125	-	-	4000	pA
Common Mode Voltage Range	V _{CMR}	I _Q = 10μA, ICL7642	25	±4.4	-	-	V
		I _Q = 1mA, ICL7641	25	±3.7	-	-	V
Output Voltage Swing	V _{OUT}	ICL7642, I _Q = 10μA, R _L = 1MΩ	25	±4.9	-	-	V
			0 to 70	±4.8	-	-	V
			-55 to 125	±4.7	-	-	V
		ICL7641, I _Q = 1mA, R _L = 10kΩ	25	±4.5	-	-	V
			0 to 70	±4.3	-	-	V
			-55 to 125	±4.0	-	-	V
Large Signal Voltage Gain	A _{VOL}	ICL7642, V _O = ±4V, R _L = 1MΩ, I _Q = 10μA	25	80	104	-	dB
			0 to 70	75	-	-	dB
			-55 to 125	68	-	-	dB
		ICL7641, V _O = ±4V, R _L = 10kΩ, I _Q = 1mA	25	76	98	-	dB
			0 to 70	72	-	-	dB
			-55 to 125	68	-	-	dB
Unity Gain Bandwidth	GBW	ICL 7642, I _Q = 10μA	25	-	0.044	-	MHz
		ICL 7641, I _Q = 1mA	25	-	1.4	-	MHz
Input Resistance	R _{IN}		25	-	10 ¹²	-	Ω
Common Mode Rejection Ratio	CMRR	ICL7642, R _S ≤ 100kΩ, I _Q = 10μA	25	70	96	-	dB
		ICL7641, R _S ≤ 100kΩ, I _Q = 1mA	25	60	87	-	dB
Power Supply Rejection Ratio (V _{SUPPLY} = ±8V to ±2V)	PSRR	ICL7642, R _S ≤ 100kΩ, I _Q = 10μA	25	80	94	-	dB
		ICL7641, R _S ≤ 100kΩ, I _Q = 1mA	25	70	77	-	dB

Electrical Specifications $V_{\text{SUPPLY}} = \pm 5\text{V}$, Unless Otherwise Specified (Continued)

PARAMETER	SYMBOL	TEST CONDITIONS	TEMP. (°C)	ICL7641E, ICL7642E			UNITS
				MIN	TYP	MAX	
Input Referred Noise Voltage	e_N	$R_S = 100\Omega$, $f = 1\text{kHz}$	25	-	100	-	$\text{nV}/\sqrt{\text{Hz}}$
Input Referred Noise Current	i_N	$R_S = 100\Omega$, $f = 1\text{kHz}$	25	-	0.01	-	$\text{pA}/\sqrt{\text{Hz}}$
Supply Current (Per Amplifier) (No Signal, No Load)	I_{SUPPLY}	ICL7642, $I_Q = 10\mu\text{A}$ Low Bias	25	-	0.01	0.03	mA
		ICL7641, $I_Q = 1\text{mA}$ High Bias	25	-	1.0	2.5	mA
Channel Separation	V_{O1}/V_{O2}	$A_V = 100$	25	-	120	-	dB
Slew Rate ($A_V = 1$, $C_L = 100\text{pF}$, $V_{\text{IN}} = 8\text{V}_{\text{P-P}}$)	SR	ICL7642, $I_Q = 10\mu\text{A}$, $R_L = 1\text{M}\Omega$	25	-	0.016	-	$\text{V}/\mu\text{s}$
		ICL7641, $I_Q = 1\text{mA}$, $R_L = 10\text{k}\Omega$	25	-	1.6	-	$\text{V}/\mu\text{s}$
Rise Time ($V_{\text{IN}} = 50\text{mV}$, $C_L = 100\text{pF}$)	t_R	ICL7642, $I_Q = 10\mu\text{A}$, $R_L = 1\text{M}\Omega$	25	-	20	-	μs
		ICL7641, $I_Q = 1\text{mA}$, $R_L = 10\text{k}\Omega$	25	-	0.9	-	μs
Overshoot Factor ($V_{\text{IN}} = 50\text{mV}$, $C_L = 100\text{pF}$)	OS	ICL7642, $I_Q = 10\mu\text{A}$, $R_L = 1\text{M}\Omega$	25	-	5	-	%
		ICL7641, $I_Q = 1\text{mA}$, $R_L = 10\text{k}\Omega$	25	-	40	-	%

Schematic Diagram



Application Information

Static Protection

All devices are static protected by the use of input diodes. However, strong static fields should be avoided, as it is possible for the strong fields to cause degraded diode junction characteristics, which may result in increased input leakage currents.

Latchup Avoidance

Junction-isolated CMOS circuits employ configurations which produce a parasitic 4-layer (PNPN) structure. The

4-layer structure has characteristics similar to an SCR, and under certain circumstances may be triggered into a low impedance state resulting in excessive supply current. To avoid this condition, no voltage greater than 0.3V beyond the supply rails may be applied to any pin. In general, the op amp supplies must be established simultaneously with, or before any input signals are applied. If this is not possible, the drive circuits must limit input current flow to 2mA to prevent latchup.

Choosing the Proper I_Q

Each device in the ICL76XX family has a similar I_Q setup scheme, which allows the amplifier to be set to nominal quiescent currents of $10\mu\text{A}$, $100\mu\text{A}$ or 1mA . These current settings change only very slightly over the entire supply voltage range. The ICL7611/12 have an external I_Q control terminal, permitting user selection of each amplifiers' quiescent current. The ICL7621 and ICL7641/7642 have fixed I_Q settings:

ICL7621 (Dual) - $I_Q = 100\mu\text{A}$

ICL7641 (Quad) - $I_Q = 1\text{mA}$

ICL7642 (Quad) - $I_Q = 10\mu\text{A}$

NOTE: The output current available is a function of the quiescent current setting. For maximum peak-to-peak output voltage swings into low impedance loads, I_Q of 1mA should be selected.

Output Stage and Load Driving Considerations

Each amplifiers' quiescent current flows primarily in the output stage. This is approximately 70% of the I_Q settings. This allows output swings to almost the supply rails for output loads of $1\text{M}\Omega$, $100\text{k}\Omega$, and $10\text{k}\Omega$, using the output stage in a highly linear class A mode. In this mode, crossover distortion is avoided and the voltage gain is maximized. However, the output stage can also be operated in Class AB for higher output currents. (See graphs under

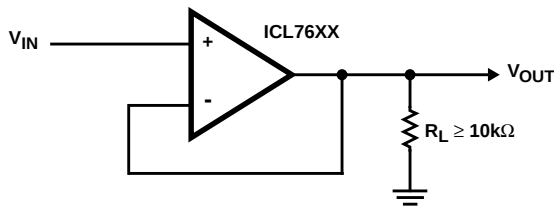
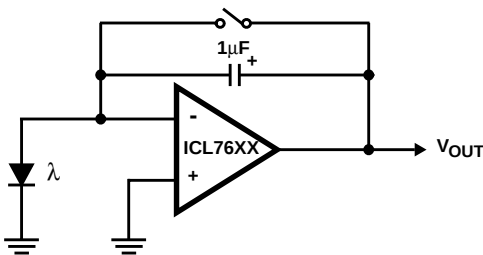


FIGURE 1. SIMPLE FOLLOWER



NOTE: Low leakage currents allow integration times up to several hours.

FIGURE 3. PHOTOCURRENT INTEGRATOR

Typical Operating Characteristics). During the transition from Class A to Class B operation, the output transfer characteristic is nonlinear and the voltage gain decreases.

Frequency Compensation

The ICL76XX are internally compensated, and are stable for closed loop gains as low as unity with capacitive loads up to 100pF .

Operation At $V_{\text{SUPPLY}} = \pm 1\text{V}$

Operation at $V_{\text{SUPPLY}} = \pm 1\text{V}$ is guaranteed for the ICL7642C only.

Output swings to within a few millivolts of the supply rails are achievable for $R_L \geq 1\text{M}\Omega$. Guaranteed input CMVR is $\pm 0.6\text{V}$ minimum and typically $+0.9\text{V}$ to -0.7V at $V_{\text{SUPPLY}} = \pm 1\text{V}$. For applications where greater common mode range is desirable, refer to the ICL7612 data sheet.

Typical Applications

The user is cautioned that, due to extremely high input impedances, care must be exercised in layout, construction, board cleanliness, and supply filtering to avoid hum and noise pickup.

Note that in no case is I_Q shown. The value of I_Q must be chosen by the designer with regard to frequency response and power dissipation.

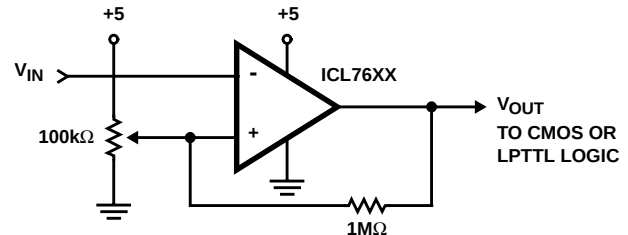
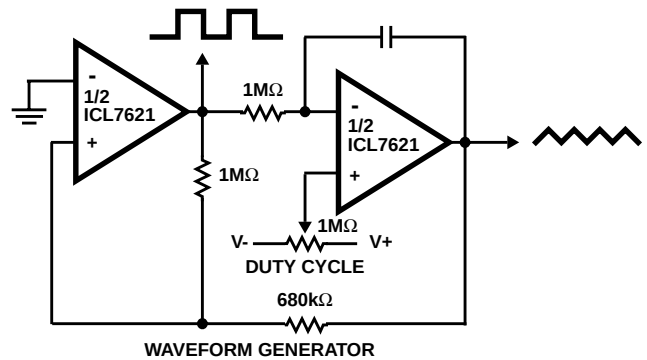
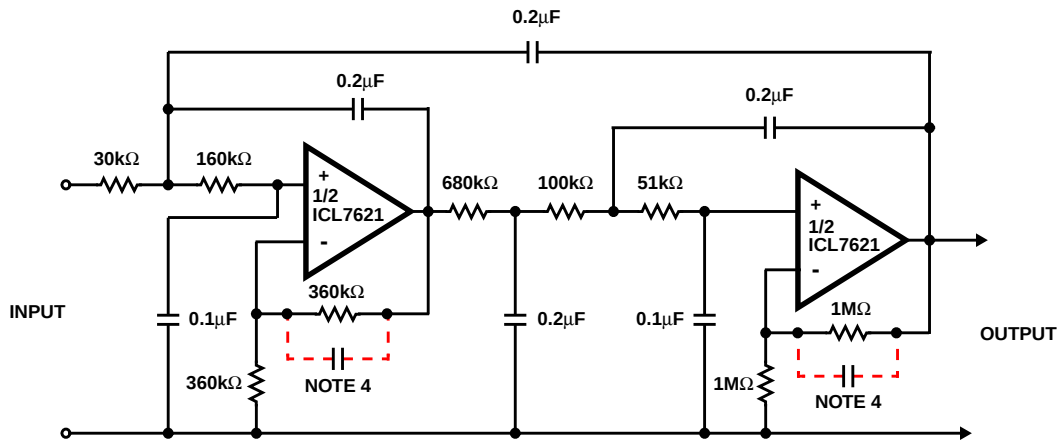
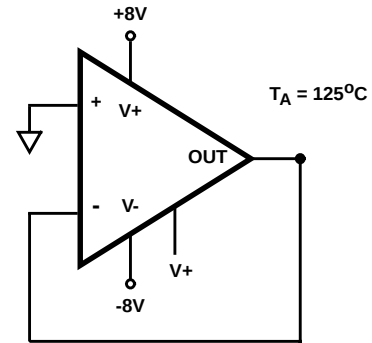


FIGURE 2. LEVEL DETECTOR

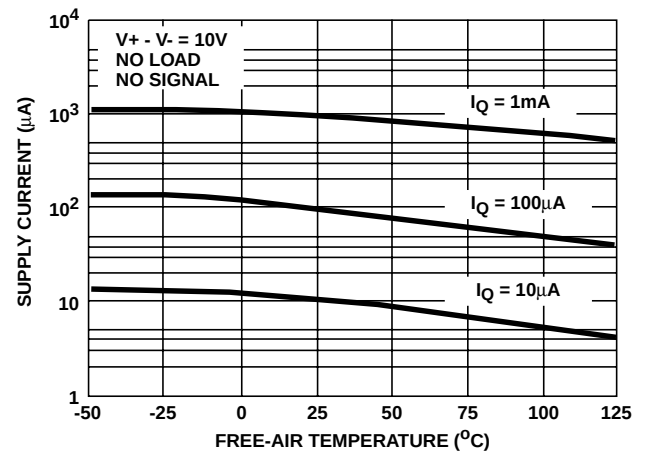


NOTE: Since the output range swings exactly from rail to rail, frequency and duty cycle are virtually independent of power supply variations.

FIGURE 4. TRIANGLE/SQUARE WAVE GENERATOR



NOTES:



Typical Performance Curves (Continued)

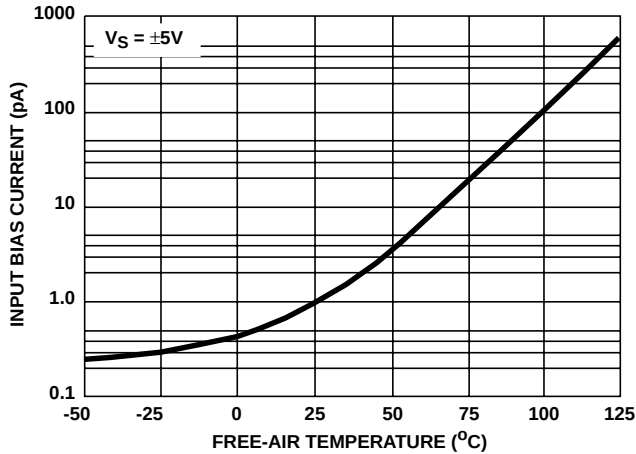


FIGURE 10. INPUT BIAS CURRENT vs TEMPERATURE

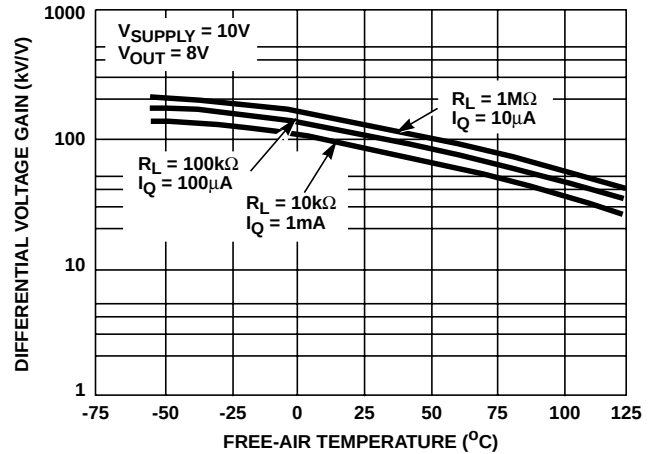


FIGURE 11. LARGE SIGNAL DIFFERENTIAL VOLTAGE GAIN vs FREE-AIR TEMPERATURE

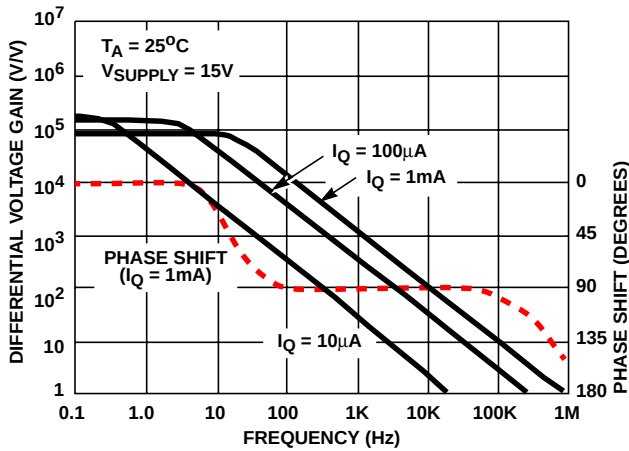


FIGURE 12. LARGE SIGNAL FREQUENCY RESPONSE

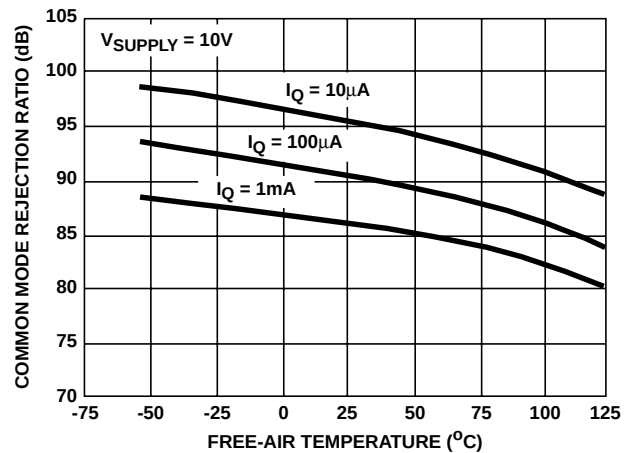


FIGURE 13. COMMON MODE REJECTION RATIO vs FREE-AIR TEMPERATURE

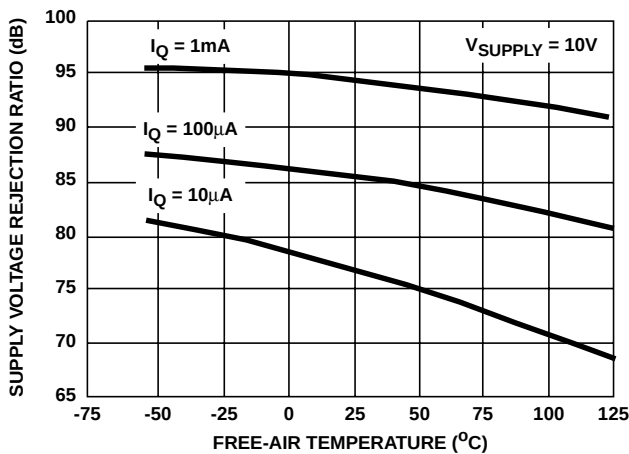


FIGURE 14. POWER SUPPLY REJECTION RATIO vs FREE-AIR TEMPERATURE

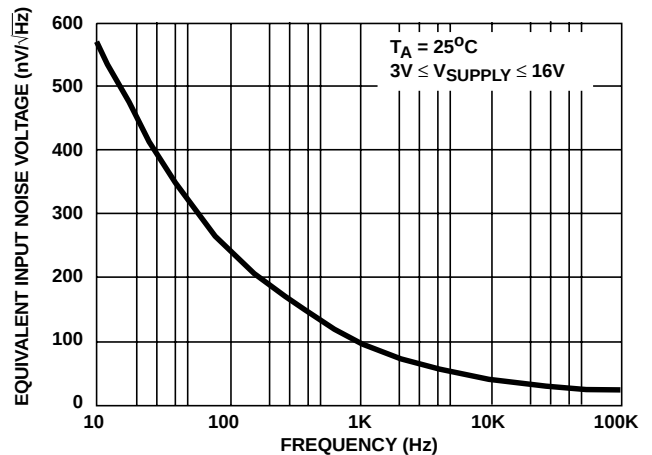


FIGURE 15. EQUIVALENT INPUT NOISE VOLTAGE vs FREQUENCY

Typical Performance Curves (Continued)

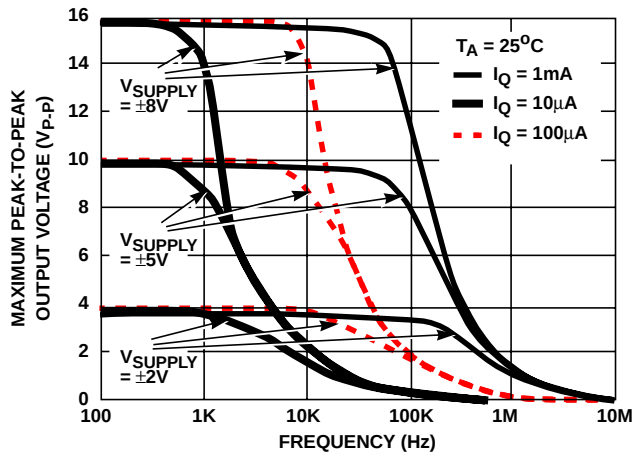


FIGURE 16. OUTPUT VOLTAGE vs FREQUENCY

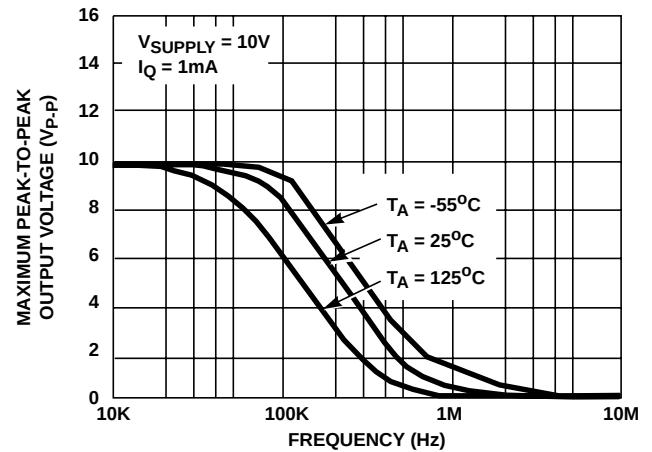


FIGURE 17. OUTPUT VOLTAGE vs FREQUENCY

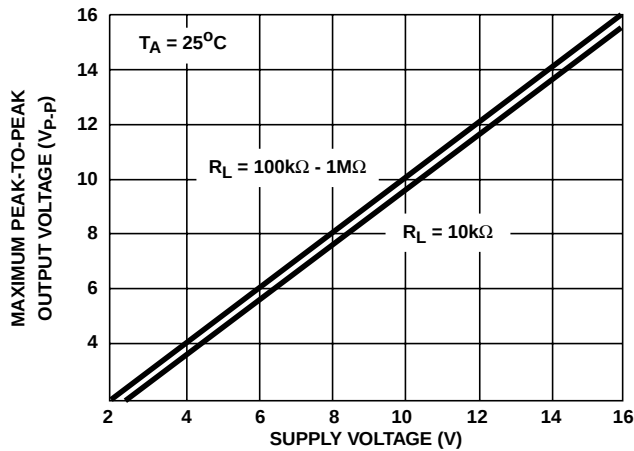


FIGURE 18. OUTPUT VOLTAGE vs SUPPLY VOLTAGE

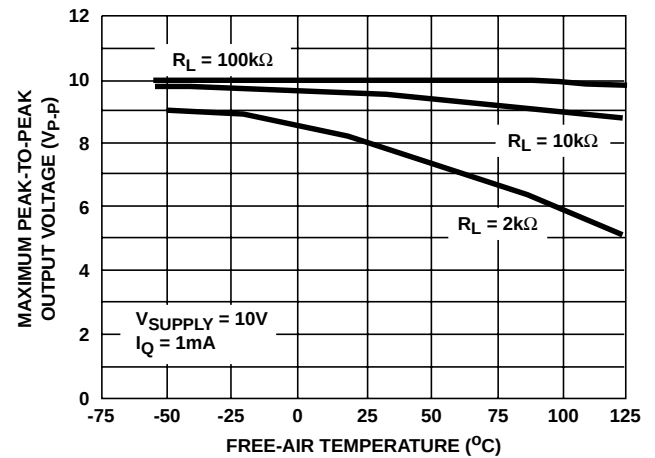


FIGURE 19. OUTPUT VOLTAGE vs FREE-AIR TEMPERATURE

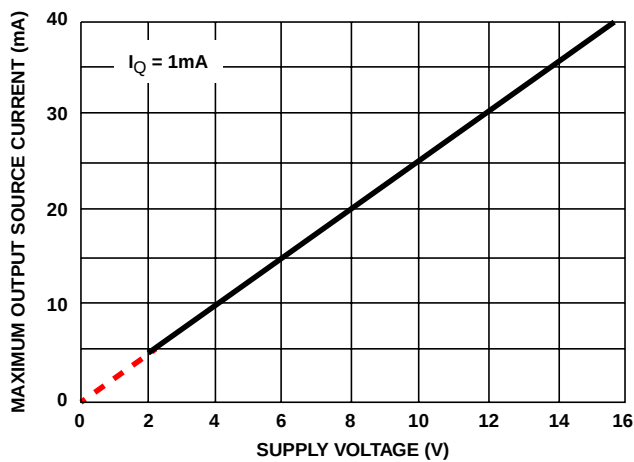


FIGURE 20. OUTPUT SOURCE CURRENT vs SUPPLY VOLTAGE

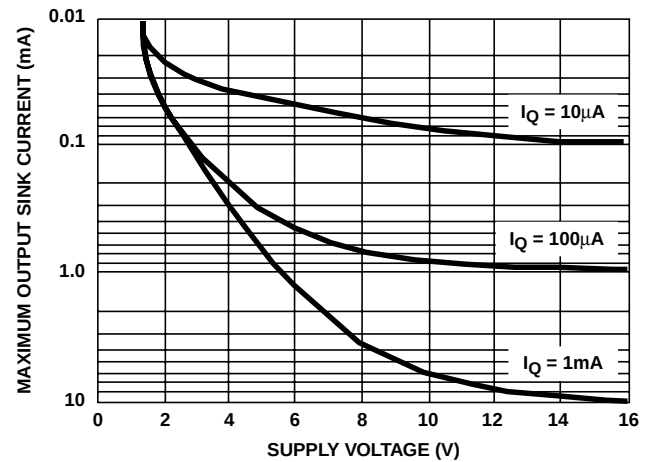


FIGURE 21. OUTPUT SINK CURRENT vs SUPPLY VOLTAGE

Typical Performance Curves (Continued)

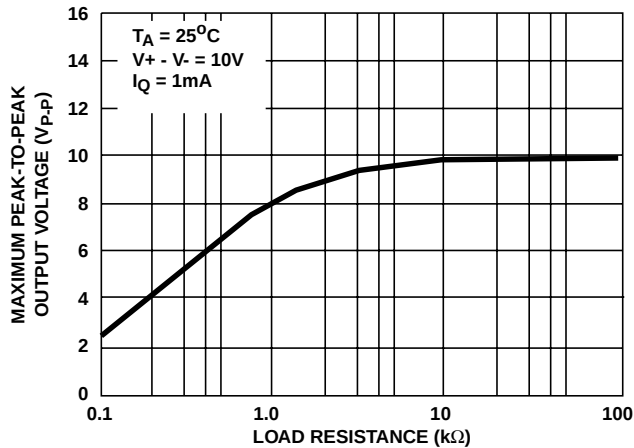


FIGURE 22. OUTPUT VOLTAGE vs LOAD RESISTANCE

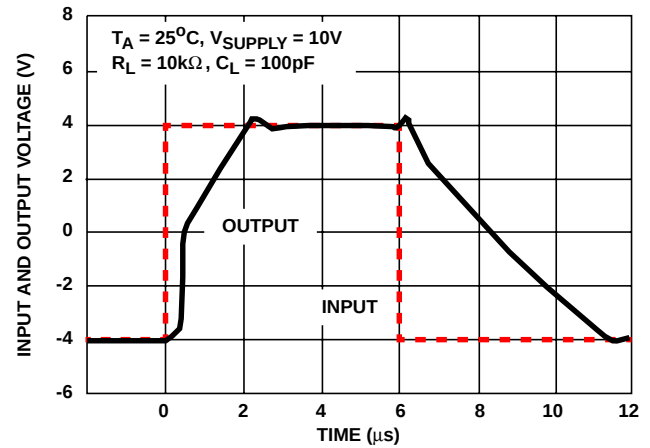


FIGURE 23. VOLTAGE FOLLOWER LARGE SIGNAL PULSE RESPONSE ($I_Q = 1\text{mA}$)

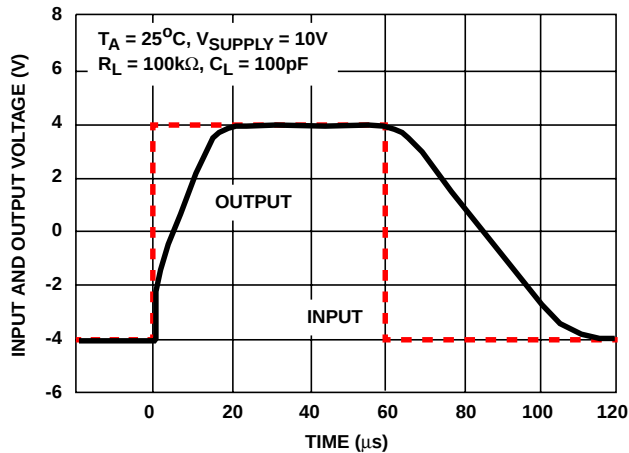


FIGURE 24. VOLTAGE FOLLOWER LARGE SIGNAL PULSE RESPONSE ($I_Q = 100\mu\text{A}$)

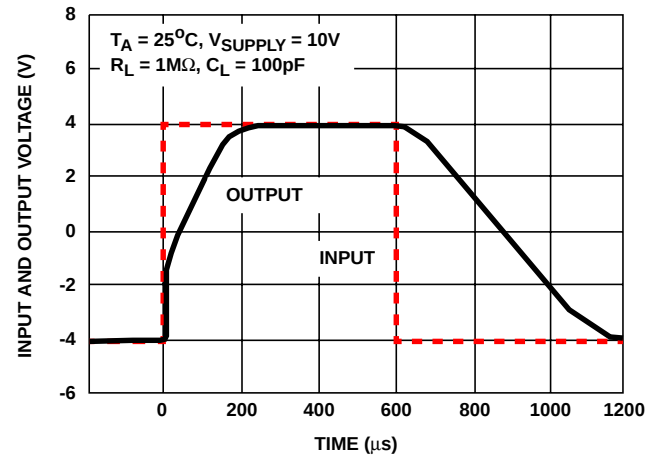


FIGURE 25. VOLTAGE FOLLOWER LARGE SIGNAL PULSE RESPONSE ($I_Q = 10\mu\text{A}$)

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